

ESD237-B1-W0201

Protection devices

TVS (Transient Voltage Suppressor)

Bi-directional, 8 V, 7 pF, 0201, RoHS and Halogen Free compliant

Quality Requirement Category: Standard

Features

- ESD / transient protection according to:
 - IEC61000-4-2 (ESD): ± 16 kV (air), ± 16 kV (contact discharge)
 - IEC61000-4-4 (EFT): ± 2 kV / ± 40 A (5/50 ns)
 - IEC61000-4-5 (surge): ± 3 A (8/20 μ s)
- Bi-directional working voltage up to: $V_{RWM} = \pm 8$ V
- Line capacitance: $C_L = 7$ pF (typical) at $f = 1$ MHz
- Clamping voltage: $V_{CL} = 13$ V (typical) at $I_{TLP} = 16$ A with $R_{DYN} = 0.21 \Omega$ (typical)
- Very low reverse current: $I_R < 1$ nA (typical)
- Minimized clamping overshoot due to extremely low parasitic inductance
- Small form factor SMD Size 0201 and low profile 0.58 mm x 0.28 mm x 0.15 mm
- Bidirectional and symmetric I/V characteristics for optimized design and assembly
- Pb-free (RoHS compliant) and halogen free package



Guidelines for optimized PCB design and assembly process are available in [\[2\]](#).

Application examples

- ESD Protection of highly susceptible IC/ASICs serving a wider usable voltage headroom
- Dedicated solution for audio PA lines to preserve uncompressed clean audio

Device information

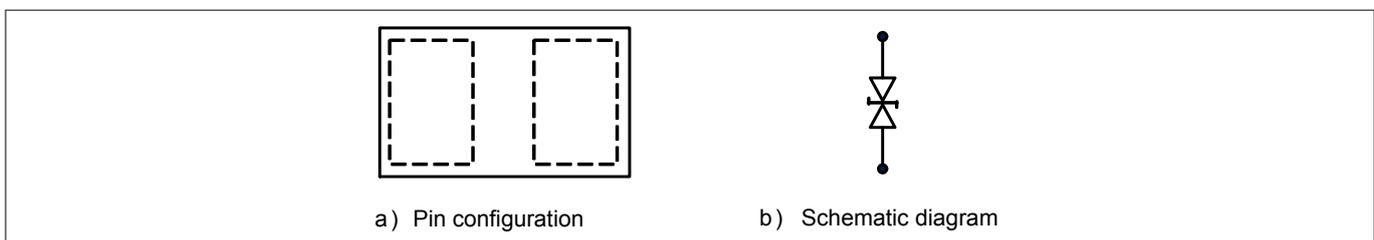


Figure 1 Pin configuration and schematic diagram

Table 1 Part information

Type	Package	Configuration	Marking code
ESD237-B1-W0201	WLL-2-1	1 line, bi-directional	YY ¹⁾

¹ The device does not have any marking on the device top. The marking code is on the pads.

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Maximum ratings

1 Maximum ratings

Note: $T_A = 25\text{ °C}$, unless otherwise specified¹⁾

Table 2 Maximum Rating

Parameter	Symbol	Values	Unit
Reverse working voltage	V_{RWM}	± 8	V
ESD discharge ²⁾	V_{ESD} (contact)	± 16	kV
	V_{ESD} (air)	± 16	
Peak pulse power ³⁾	P_{PK}	42	W
Peak pulse current ³⁾	I_{PP}	± 3	A
Operating temperature range	T_{OP}	-55 to 85	°C
Storage temperature	T_{stg}	-55 to 150	°C

Attention: *Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component.*

¹ Device is electrically symmetrical

² V_{ESD} according to IEC61000-4-2 (R = 330 Ω , C = 150 pF discharge network)

³ Stress pulse: 8/20 μ s current waveform according to IEC61000-4-5

Electrical characteristics

2 Electrical characteristics

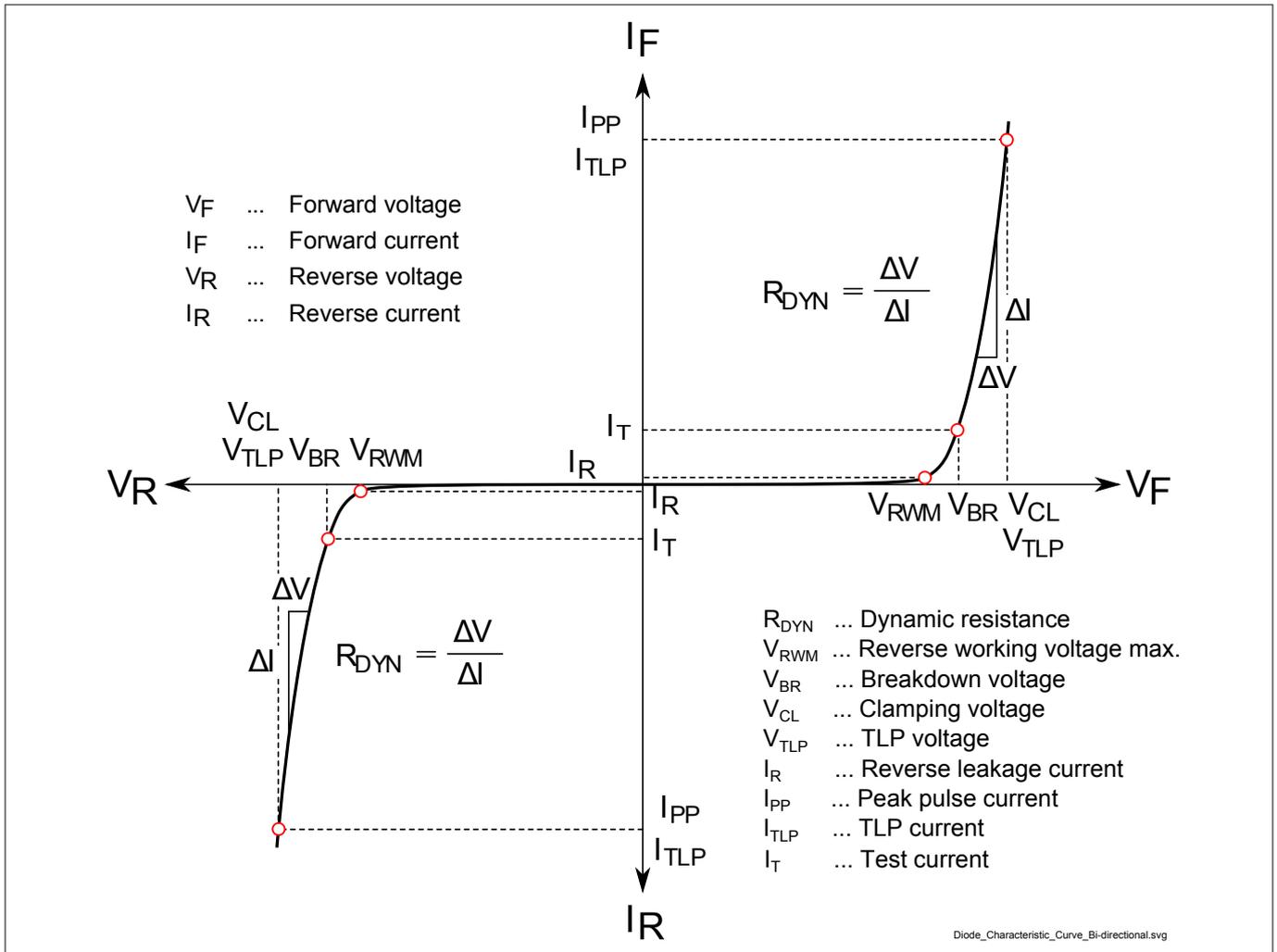


Figure 2 Definitions of electrical characteristics

Electrical characteristics

Table 3 DC characteristics ($T_A = 25\text{ °C}$, unless otherwise specified) ¹⁾

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Breakdown voltage	V_{BR}	9	10.5	12	V	$I_T = 1\text{ mA}$
Reverse current	I_R	–	–	100	nA	$V_R = 8\text{ V}$

Table 4 AC characteristics ($T_A = 25\text{ °C}$, unless otherwise specified)

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	7	–	pF	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$
		–	7	–		$V_R = 0\text{ V}$, $f = 1\text{ GHz}$

Table 5 ESD and surge characteristics ($T_A = 25\text{ °C}$, unless otherwise specified) ¹⁾

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Clamping voltage ²⁾	V_{CL}	–	13	–	V	$I_{TLP} = 16\text{ A}$, $t_p = 100\text{ ns}$
		–	17	–		$I_{TLP} = 30\text{ A}$, $t_p = 100\text{ ns}$
Clamping voltage ³⁾		–	10	–		$I_{PP} = 1\text{ A}$, $t_p = 8/20\text{ }\mu\text{s}$
		–	12	–		$I_{PP} = 3\text{ A}$, $t_p = 8/20\text{ }\mu\text{s}$
Dynamic resistance ²⁾	R_{DYN}	–	0.21		Ω	$t_p = 100\text{ ns}$

¹ Device is electrically symmetrical

² Please refer to Application Note AN210 [1]. TLP parameters: $Z_0 = 50\text{ }\Omega$, $t_p = 100\text{ ns}$, $t_r = 0.6\text{ ns}$.

³ Stress pulse: 8/20 μs current waveform according to IEC61000-4-5

Typical characteristics diagrams

3 Typical characteristics diagrams

Note: $T_A = 25\text{ }^\circ\text{C}$, unless otherwise specified

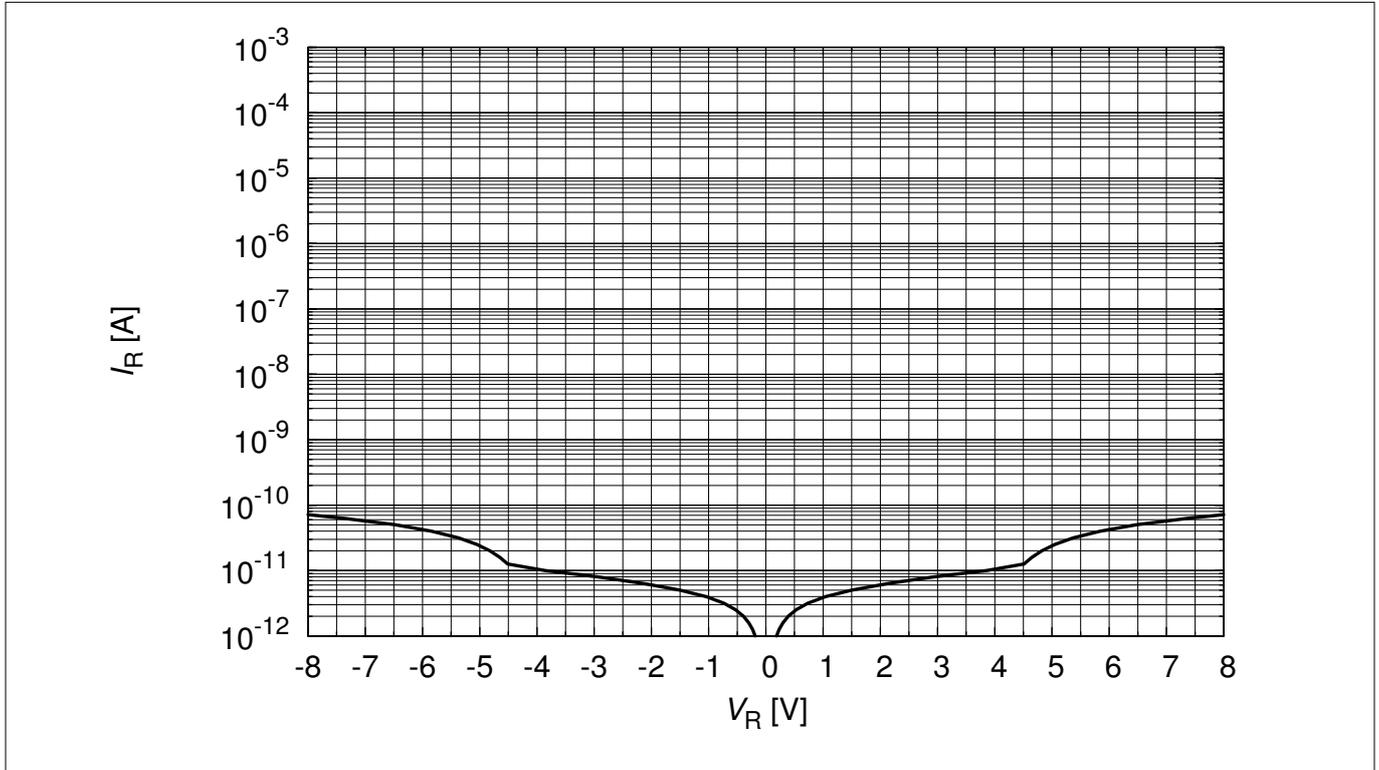


Figure 3 Reverse leakage current: $I_R = f(V_R)$

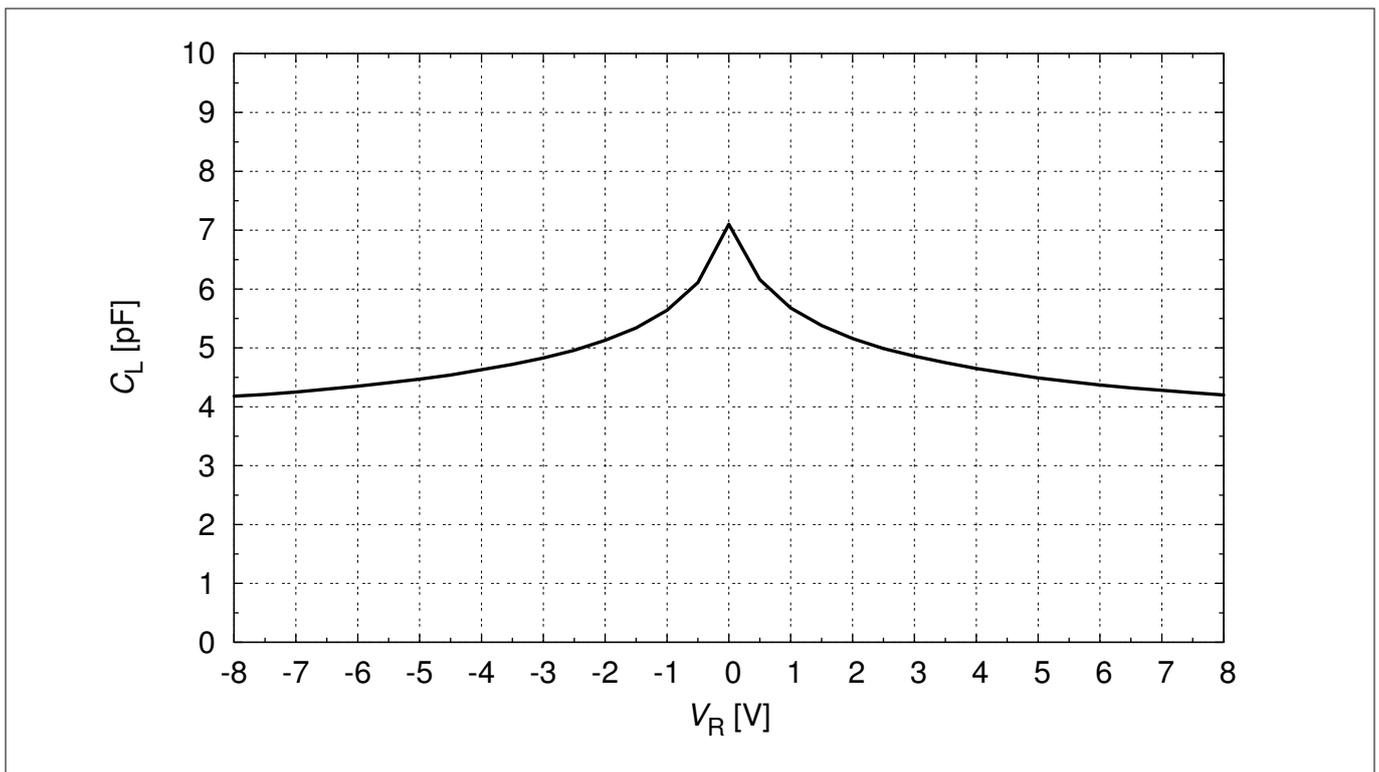


Figure 4 Line capacitance: $C_L = f(V_R)$, $f = 1\text{ MHz}$

Typical characteristics diagrams

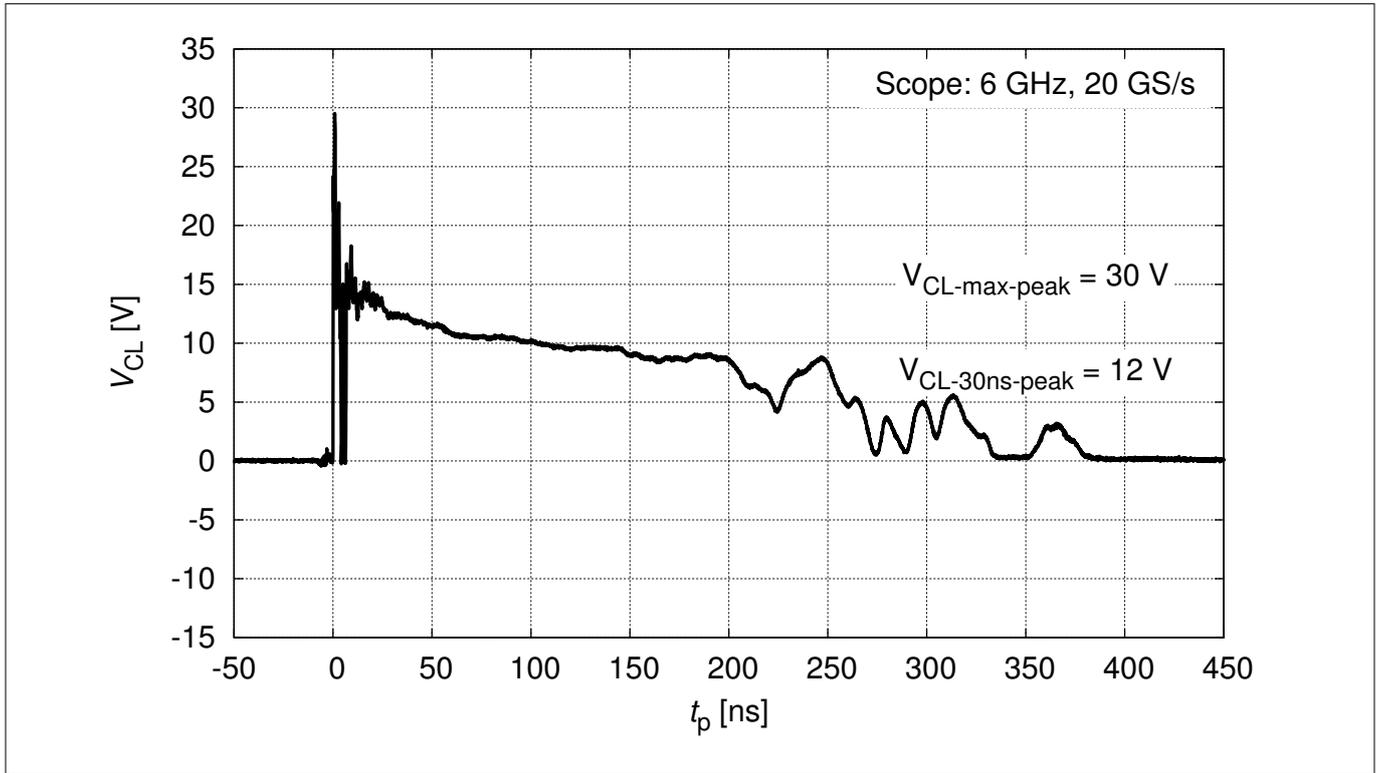


Figure 5 Clamping voltage (ESD): $V_{CL} = f(t)$, 8 kV positive pulse

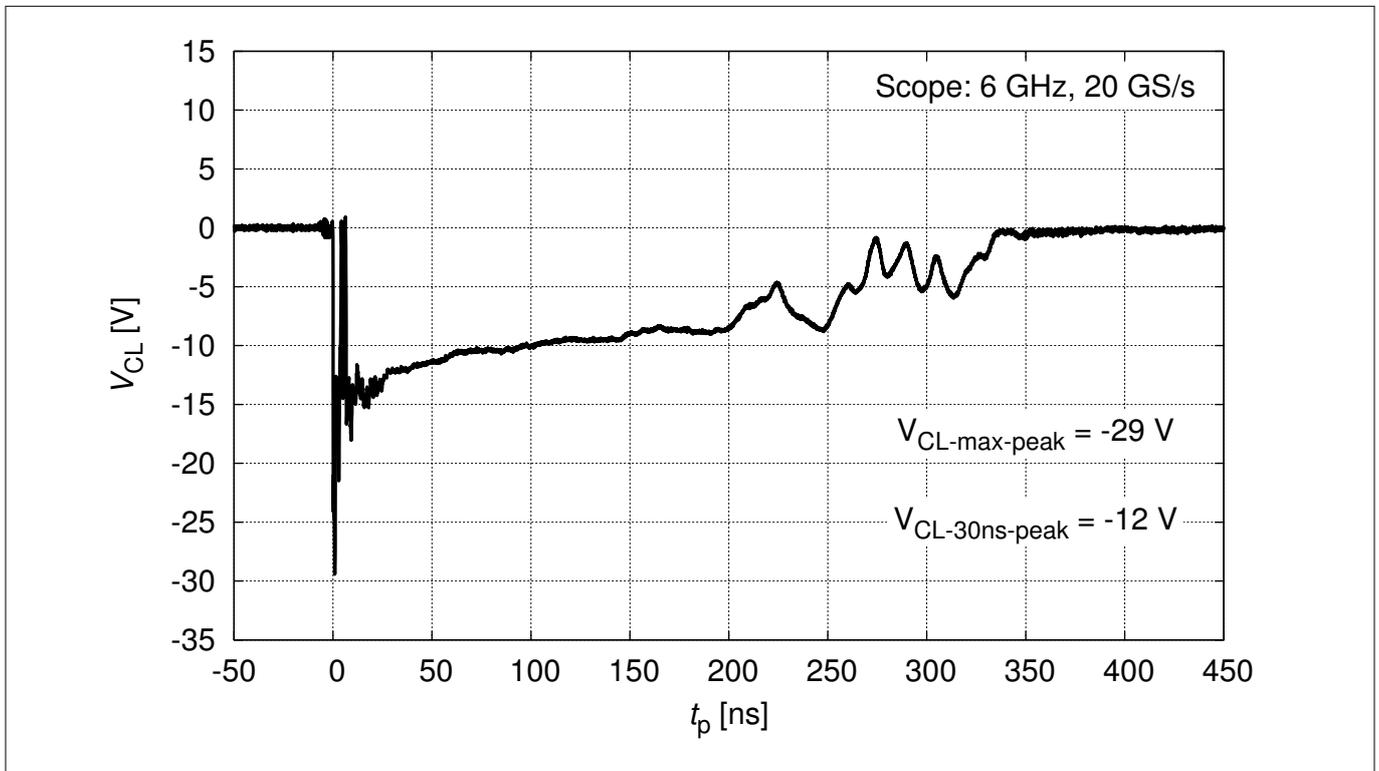


Figure 6 Clamping voltage (ESD): $V_{CL} = f(t)$, 8 kV negative pulse

Typical characteristics diagrams

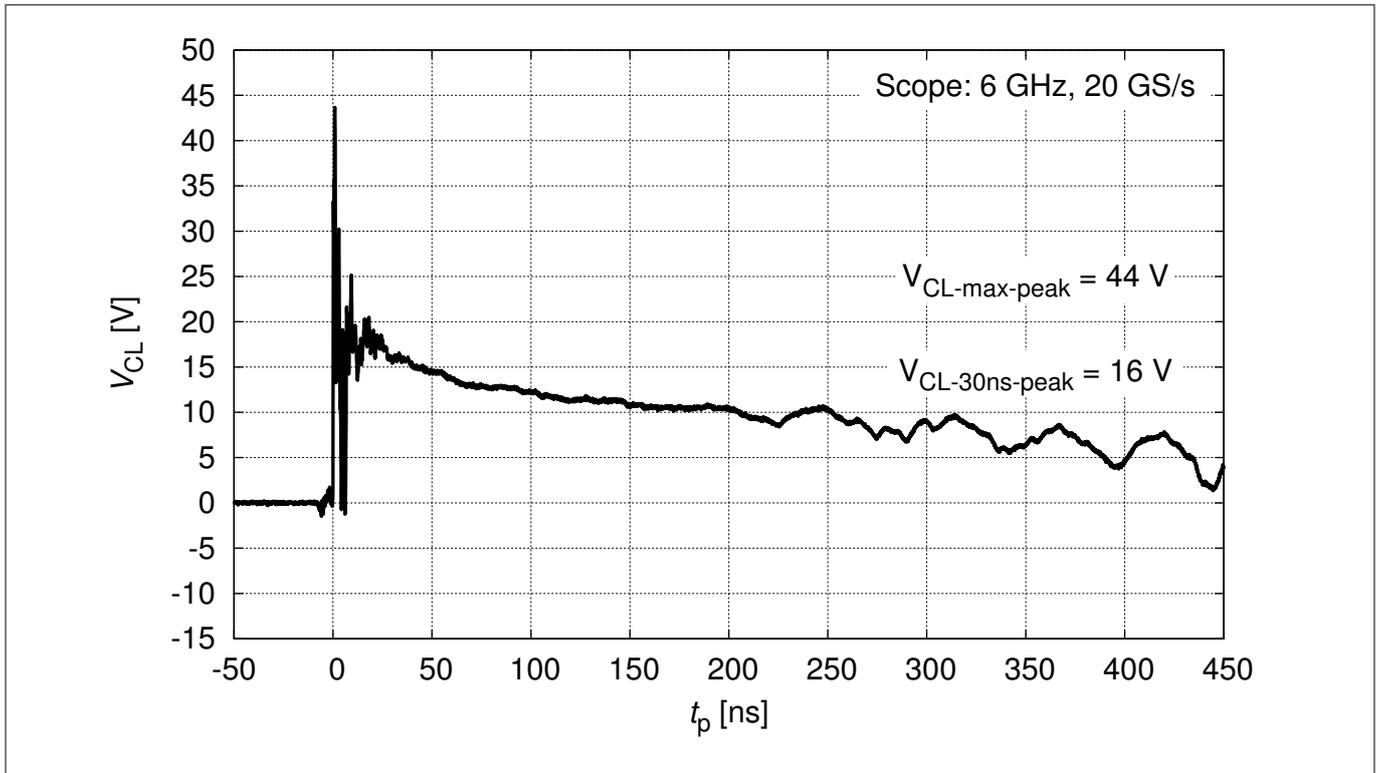


Figure 7 Clamping voltage (ESD): $V_{CL} = f(t)$, 15 kV positive pulse

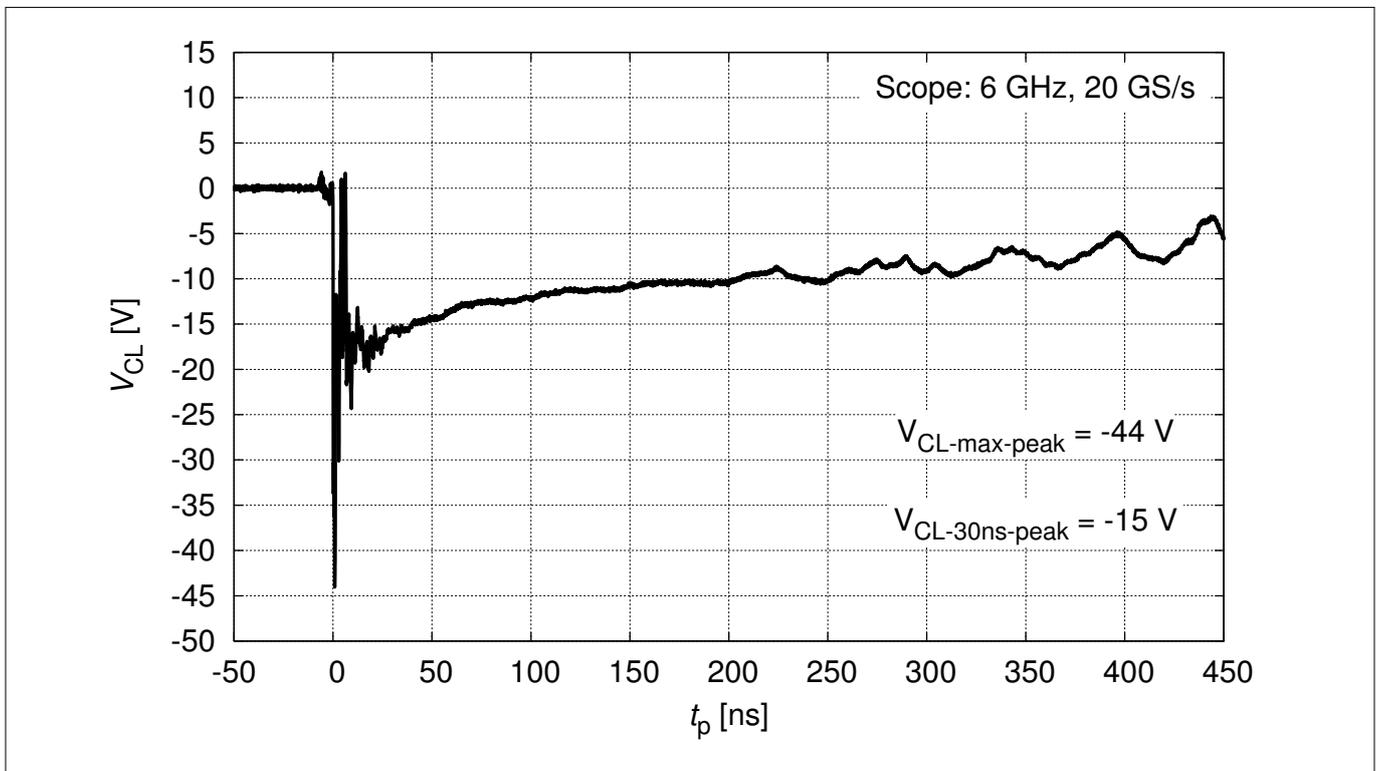


Figure 8 Clamping voltage (ESD): $V_{CL} = f(t)$, 15 kV negative pulse

Typical characteristics diagrams

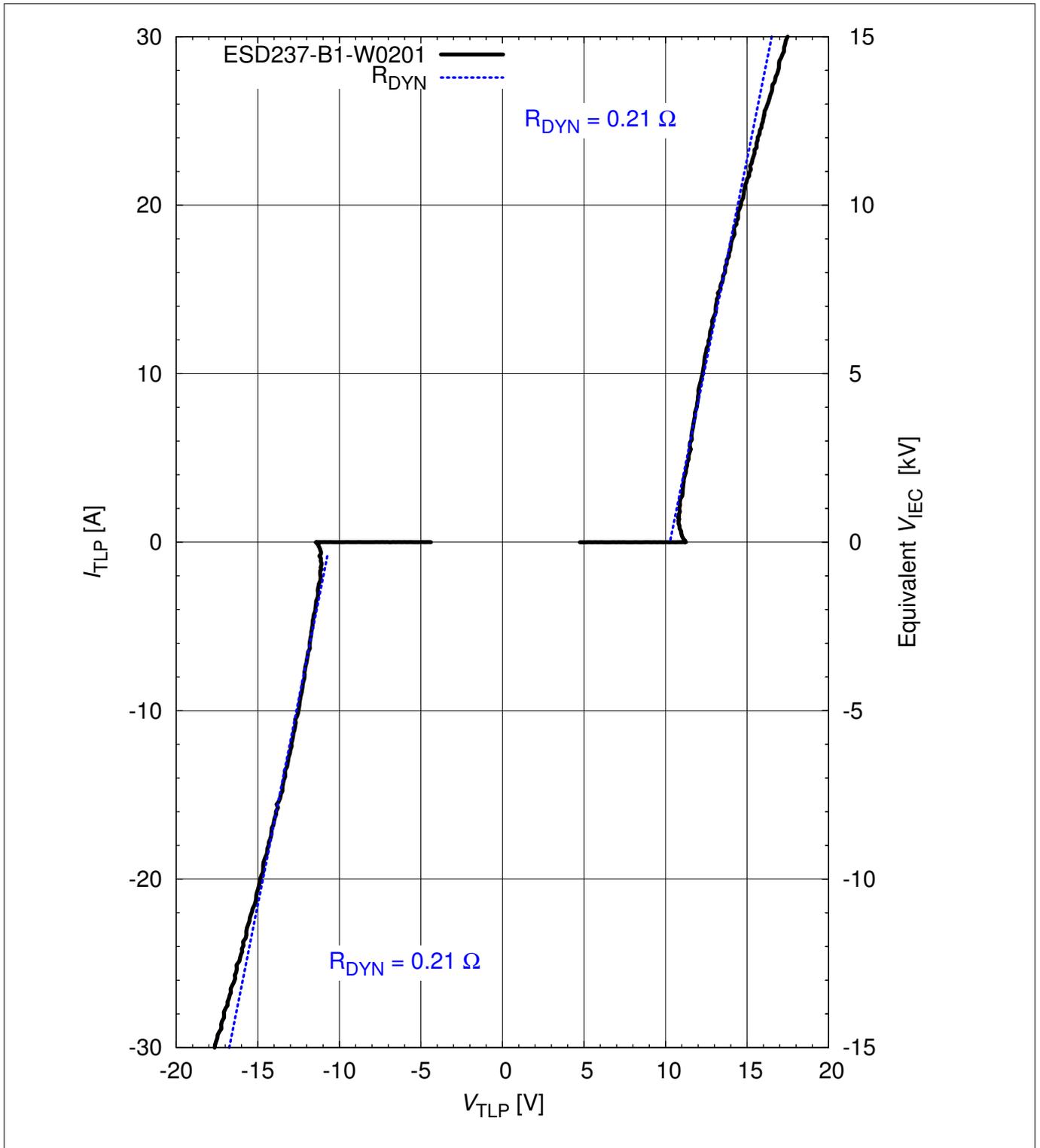


Figure 9 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ [1]

Typical characteristics diagrams

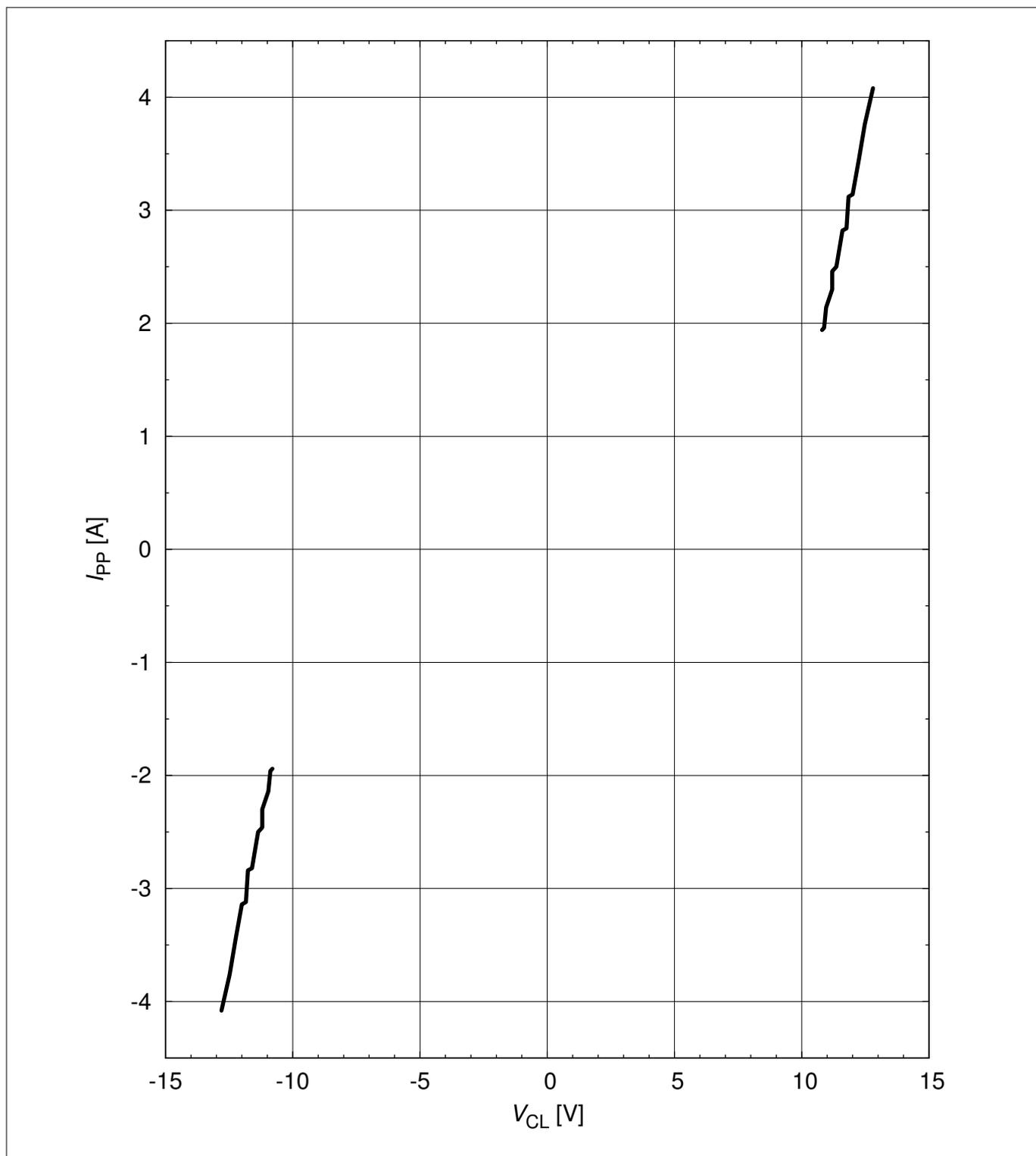


Figure 10 Clamping voltage (Surge): $I_{PP} = f(V_{CL})$ [1]

Typical characteristics diagrams

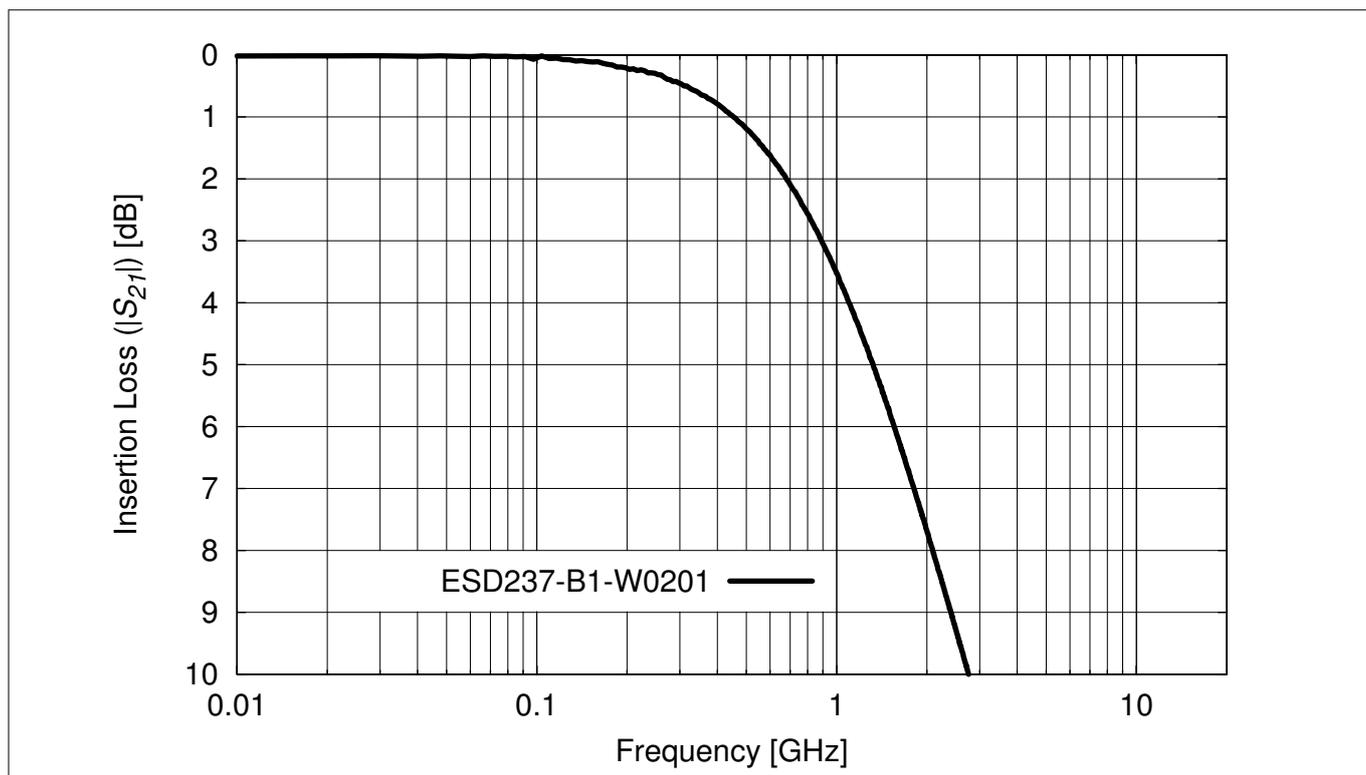


Figure 11 Insertion loss vs. frequency in a 50 Ω system

Package information

4 Package information

4.1 WLL-2-1 package

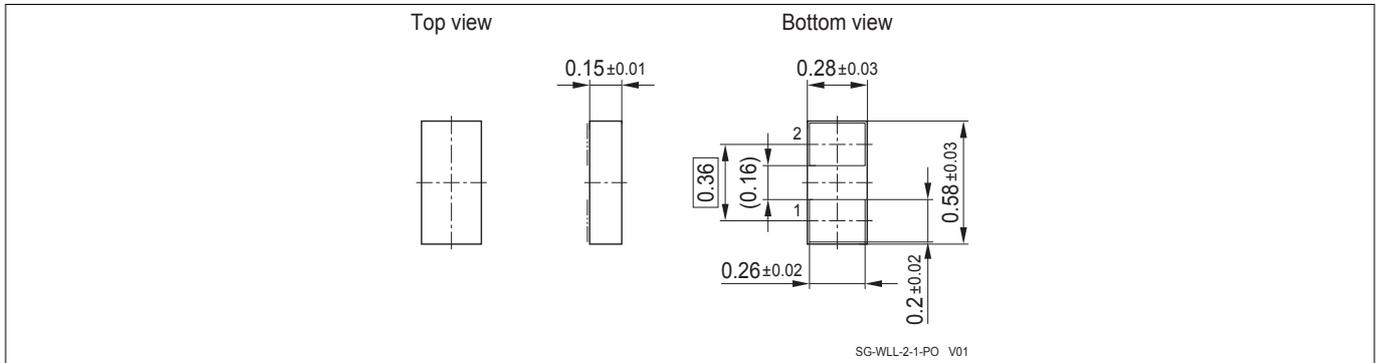


Figure 12 WLL-2-1 package outline (dimension in mm)

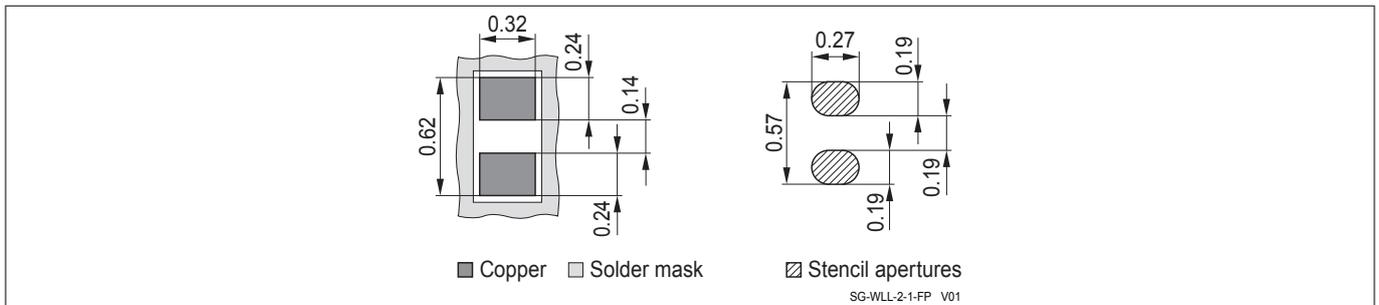


Figure 13 WLL-2-1 footprint (dimension in mm), Recommendations for Printed Circuit Board Assembly see [2]

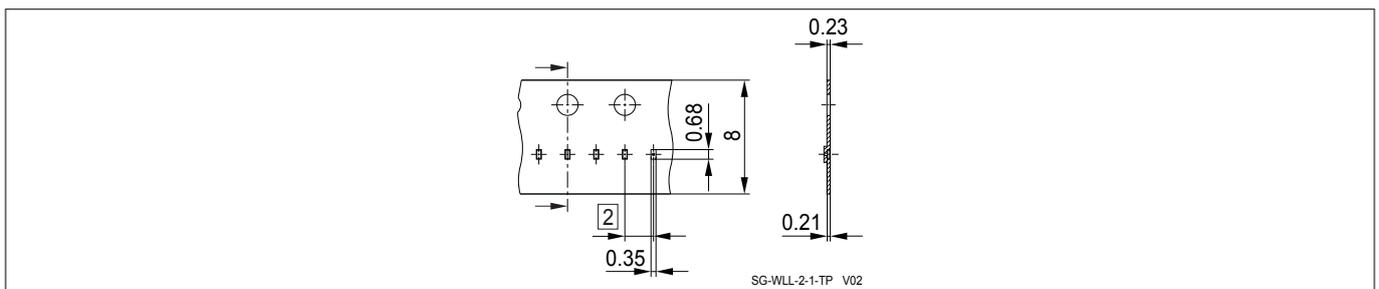


Figure 14 WLL-2-1 packing (dimension in mm)

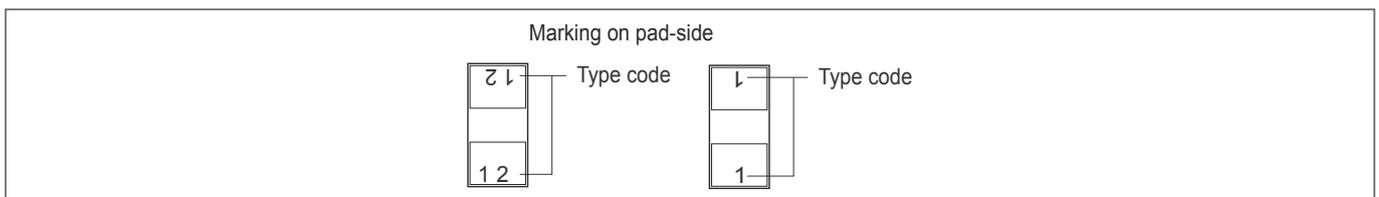


Figure 15 WLL-2-1 marking example (see also Table 1)

References

5 References

- [1] Infineon AG - **Application Note AN210**: Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology
- [2] Infineon AG - Recommendation for Printed Circuit Board Assembly of Infineon WLL Packages
http://www.infineon.com/Packageinformation_WLL
- [3] Infineon AG - **Application Note AN392**: TVS Diodes in ChipScalePackage reduce size and save cost

Revision History

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Page or Item	Subjects (major changes since previous revision)
Revision 1.0, 2016-10-18	
All	Status change to final

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Email: erratum@infineon.com

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

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